





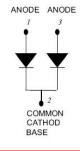
### 303CNQ080/303CNQ100 SCHOTTKY RECTIFIER



#### **Features**

- 175°C T<sub>J</sub> operation
- · Center tap module
- High purity, high temperature epoxy encapsulation for
- · enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# **Circuit Diagram**



### **Applications**

- · High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	$V_{RRM} \ V_{RWM}$	-	80	303CNQ080	V
DC Blocking Voltage	VRWM VR		100	303CNQ100	V
Average Rectified Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =126°C,	150(Per Leg)		A
	rectang	rectangular wave form	300(Per Device)		
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	3000		Α
Non-Repetitive Avalanche Energy(Peg Leg)	E <sub>AS</sub>	T <sub>J</sub> =25°C,I <sub>AS</sub> =1A,L=30mH	15		mJ
Repetitive Avalanche Current (Peg Leg)	I <sub>AR</sub>	Current decaying linearly to zero in 1 μsec Frequency limited by T <sub>J</sub> max. V <sub>A</sub> =1.5×V <sub>R</sub> typical	1		А

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •









## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 150A, Pulse, T <sub>J</sub> = 25 °C @ 300A, Pulse, T <sub>J</sub> = 25 °C	0.74 0.84	0.91 1.09	V
	V <sub>F2</sub>	@ 150A, Pulse, T <sub>J</sub> = 125 °C @ 300A, Pulse, T <sub>J</sub> = 125 °C	0.59 0.70	0.72 0.85	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25  ^{\circ}\text{C}$	0.002	4.5	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R_i} T_J = 125  ^{\circ}\text{C}$	1	60	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	3600	4150	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specific	Units	
Junction Temperature	TJ	-	-55 to +175		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175		°C
Typical Thermal Resistance Junction to Case(Per leg)	$R_{ heta JC}$	DC operation	0.4	0	°C/W
Typical Thermal Resistance Junction to Case(Per package)	$R_{ heta JC}$	DC operation	0.20		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.10		°C/W
Mounting Torque	Тм	-	Mounting Torque	24(min) 35(max)	- Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	79 g		
Case Style	PRM4 Non-Isolated				

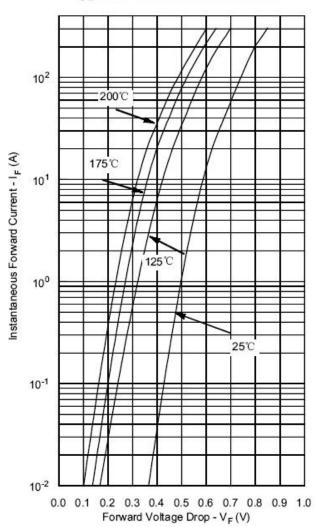




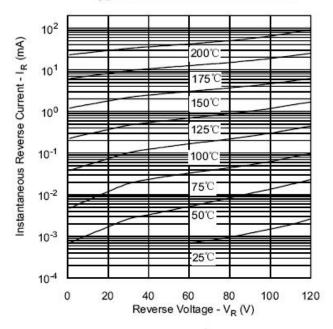


## **Ratings and Characteristics Curves**

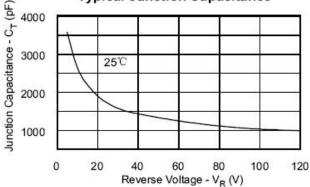
### **Typical Forward Characteristics**



### Typical Reverse Characteristics







<sup>•</sup> China - Germany - Korea - Singapore - United States •

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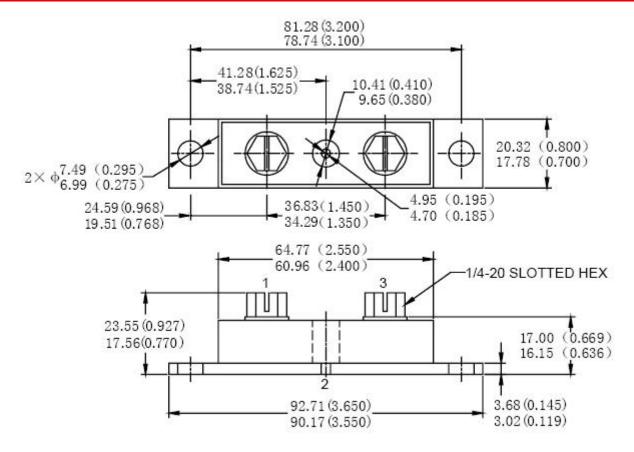




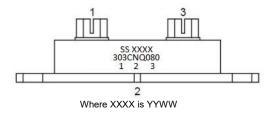




### **Mechanical Dimensions PRM4 Non-Isolated(Millimeters/Inches)**



### **Marking Diagram**



303CNQ080 = Part name SS YY = SS = Year ww = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping
303CNQ SERIES	PRM4(Non- Isolated) (Pb-Free)	9 pcs/box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.









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